

# **Isc N-Channel MOSFET Transistor**

## IPA50R299CP

#### FEATURES

- With TO-220F package
- · Low input capacitance and gate charge
- · Low gate input resistance
- Reduced switching and conduction losses
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



## APPLICATIONS

· Switching applications

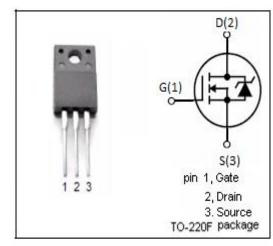


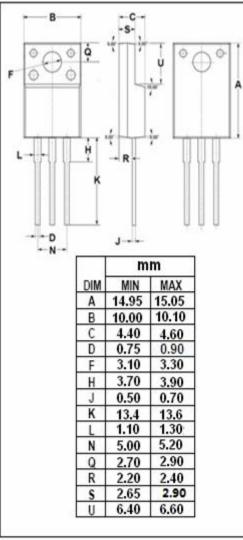
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL           | PARAMETER                                                              | VALUE   | UNIT         |
|------------------|------------------------------------------------------------------------|---------|--------------|
| V <sub>DSS</sub> | Drain-Source Voltage                                                   | 500     | V            |
| V <sub>GSS</sub> | Gate-Source Voltage                                                    | ±30     | V            |
| I <sub>D</sub>   | Drain Current-Continuous @Tc=25°C<br>(V <sub>GS</sub> at 10V) Tc=100°C | 12<br>8 | А            |
| I <sub>DM</sub>  | Drain Current-Single Pulsed                                            | 26      | Α            |
| P <sub>D</sub>   | Total Dissipation @Tc=25℃                                              | 104     | W            |
| Tj               | Max. Operating Junction Temperature                                    | 150     | °C           |
| T <sub>stg</sub> | Storage Temperature                                                    | -40~150 | $^{\circ}$ C |

## THERMAL CHARACTERISTICS

| SYMBOL    | PARAMETER                             | MAX | UNIT |
|-----------|---------------------------------------|-----|------|
| Rth(ch-c) | Channel-to-case thermal resistance    | 2.8 | °C/W |
| Rth(ch-a) | Channel-to-ambient thermal resistance | 62  | °C/W |







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### **ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25℃ unless otherwise specified

| SYMBOL              | PARAMETER                      | CONDITIONS                                                                                                     | MIN | ТҮР | MAX      | UNIT |
|---------------------|--------------------------------|----------------------------------------------------------------------------------------------------------------|-----|-----|----------|------|
| BV <sub>DSS</sub>   | Drain-Source Breakdown Voltage | V <sub>GS</sub> =0V; I <sub>D</sub> =0.25mA                                                                    | 500 |     |          | V    |
| V <sub>GS(th)</sub> | Gate Threshold Voltage         | V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =0.44mA                                                     | 2.5 |     | 3.5      | V    |
| R <sub>DS(on)</sub> | Drain-Source On-Resistance     | V <sub>GS</sub> = 10V; I <sub>D</sub> =6.6A                                                                    |     | 270 | 299      | mΩ   |
| I <sub>GSS</sub>    | Gate-Source Leakage Current    | V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V                                                                    |     |     | ±0.1     | μА   |
| I <sub>DSS</sub>    | Drain-Source Leakage Current   | V <sub>DS</sub> = 500V; V <sub>GS</sub> = 0V;Tj=25°C<br>V <sub>DS</sub> = 500V; V <sub>GS</sub> = 0V; Tj=150°C |     |     | 1<br>100 | μА   |
| V <sub>SDF</sub>    | Diode forward voltage          | I <sub>SD</sub> =6.6A, V <sub>GS</sub> = 0 V                                                                   |     |     | 1.2      | V    |

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